

GNSS LOW NOISE AMPLIFIER GaAs MMIC

■ GENERAL DESCRIPTION

The NJG1143UA2 is a low noise amplifier GaAs MMIC designed for GNSS (Global navigation Satellite Systems).

The NJG1143UA2 is featured very small size, low noise figure, high gain and low current consumption. The NJG1143UA2 operates from 1.5V to 3.6V single voltage between -40 and 105°C, has stand-by mode to save the supply current, and requires only three external components. The NJG1143UA2 has an on-chip ESD protection. The NJG1143UA2 is available in a very small, lead-free, halogen-free, 1.0mm x 1.0mm x 0.37 mm, 6-pin EPFFP6-A2 package.

■ PACKAGE OUTLINE



NJG1143UA2

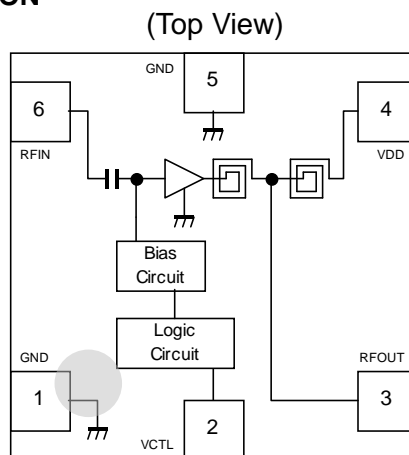
■ APPLICATION

GNSS applications like GPS, Galileo, GLONASS and COMPASS

■ FEATURES

- Low supply voltage +2.85V typ. (+1.5V to +3.6V)
- Low control voltage +1.8V typ. (+1.5V to +3.6V)
- Low current consumption 4.0mA typ. @V_{DD}=2.85V, V_{CTL}=1.8V
- High gain 7μA typ. @V_{DD}=2.85V, V_{CTL}=0V, Stand-by mode
- Low noise figure 20.0dB typ. @V_{DD}=2.85V, V_{CTL}=1.8V, f=1575MHz
- Input power at 1dB gain compression point 0.70dB typ. @V_{DD}=2.85V, V_{CTL}=1.8V, f=1575MHz
- High input IP3 -16.5dBm typ. @V_{DD}=2.85V, V_{CTL}=1.8V, f=1575MHz
- Stand-by function -2.0dBm typ. @V_{DD}=2.85V, V_{CTL}=1.8V, f=1575+1575.1MHz
- Small package size EPFFP-A2 (Package size: 1.0mmx1.0mmx0.37mm typ.)
- Integrated ESD protection circuit
- Lead-free and halogen-free, MSL1

■ PIN CONFIGURATION



Pin Connection

1. GND
2. VCTL
3. RFOUT
4. VDD
5. GND
6. RFIN

■ TRUTH TABLE

“H”=V_{CTL}(H), “L”=V_{CTL}(L)

VCTL	LNA Mode
H	Active mode
L	Stand-by mode

Note: Specifications and description listed in this datasheet are subject to change without notice.

NJG1143UA2

■ ABSOLUTE MAXIMUM RATINGS

$T_a=+25^{\circ}\text{C}$, $Z_s=Z_i=50\Omega$

PARAMETERS	SYMBOL	CONDITIONS	RATINGS	UNITS
Supply voltage	V_{DD}		5.0	V
Control voltage	V_{CTL}		5.0	V
Input power	P_{IN}	$V_{DD}=2.85\text{V}$	+15	dBm
Power dissipation	P_D	4-layer FR4 PCB with through-hole (101.5mmx114.5mm), $T_j=150^{\circ}\text{C}$	590	mW
Operating temperature	T_{opr}		-40 to +105	$^{\circ}\text{C}$
Storage temperature	T_{stg}		-55 to +150	$^{\circ}\text{C}$

■ ELECTRICAL CHARACTERISTICS 1 (DC)

(General conditions: $T_a=+25^{\circ}\text{C}$, $Z_s=Z_i=50\Omega$)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	V_{DD}	VDD Terminal	1.5	-	3.6	V
Control Voltage (High)	$V_{CTL(H)}$	VCTL Terminal	1.5	1.8	3.6	V
Control Voltage (Low)	$V_{CTL(L)}$	VCTL Terminal	0	0	0.3	V
Supply Current 1	I_{DD1}	Active mode VDD Terminal $V_{DD}=2.85\text{V}$, $V_{CTL}=1.8\text{V}$	-	4.0	6.5	mA
Supply Current 2	I_{DD2}	Active mode VDD Terminal $V_{DD}=1.8\text{V}$, $V_{CTL}=1.8\text{V}$	-	3.0	4.7	mA
Supply Current 3	I_{DD3}	Stand-by mode VDD Terminal $V_{DD}=2.85\text{V}$, $V_{CTL}=0\text{V}$	-	7.0	15.0	μA
Supply Current 4	I_{DD4}	Stand-by mode VDD Terminal $V_{DD}=1.8\text{V}$, $V_{CTL}=0\text{V}$	-	4.0	10.0	μA
Control Current	I_{CTL}	$V_{CTL}=1.8\text{V}$, VCTL Terminal	-	5.0	12.0	μA

■ ELECTRICAL CHARACTERISTICS 2 (RF, $V_{DD}=2.85V$)

(General conditions: $V_{DD}=2.85V$, $V_{CTL}=1.8V$, Freq=1.575GHz, $T_a=+25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Small Signal Gain 1	Gain1		17.5	20.0	22.0	dB
Noise Figure 1	NF1	Exclude PCB and connector Losses (0.08dB)	-	0.70	0.95	dB
Input Power at 1dB Gain Compression Point 1	P-1dB(IN) ₁		-19.0	-16.5	-	dBm
Input 3rd Order Intercept Point 1	IIP3 ₁	2 tone, 100k spacing Pin=-34dBm	-6.0	-2.0	-	dBm
RF Input Port VSWR 1	VSWR _{i1}		-	1.5	2.0	
RF Output Port VSWR 1	VSWR _{o1}			1.5	2.0	

■ ELECTRICAL CHARACTERISTICS 3 (RF, $V_{DD}=1.8V$)

(General conditions: $V_{DD}=1.8V$, $V_{CTL}=1.8V$, Freq=1.575GHz, $T_a=+25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Small Signal Gain 2	Gain2		16.5	19.0	21.0	dB
Noise Figure 2	NF2	Exclude PCB and connector Losses (0.08dB)	-	0.75	1.10	dB
Input Power at 1dB Gain Compression Point 2	P-1dB(IN) ₂		-22.0	-19.5	-	dBm
Input 3rd Order Intercept Point 2	IIP3 ₂	2 tone, 100k spacing Pin=-34dBm	-10.0	-6.0	-	dBm
RF Input Port VSWR 2	VSWR _{i2}		-	1.5	2.3	
RF Output Port VSWR 2	VSWR _{o2}			1.3	1.7	

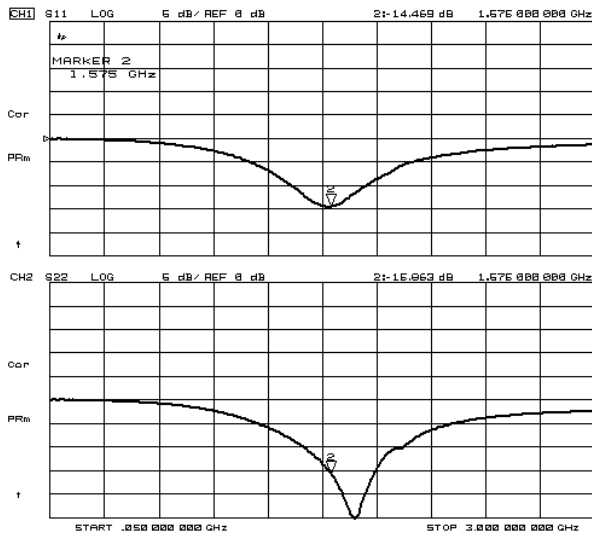
NJG1143UA2

■ TERMINAL INFORMATION

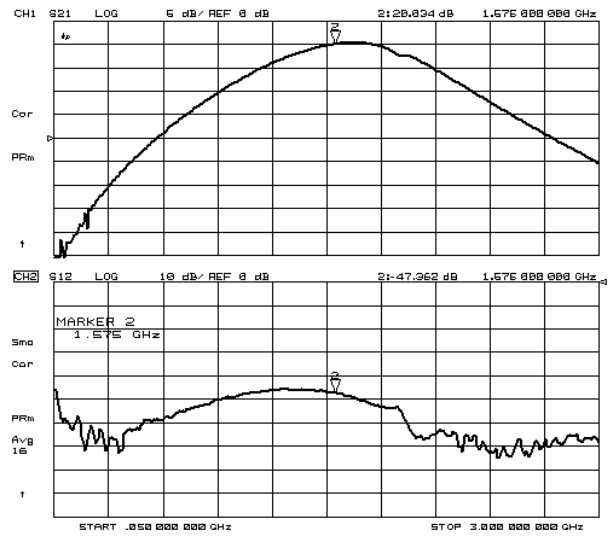
No.	SYMBOL	DESCRIPTION
1	GND	Ground terminal. These terminals should be connected to the ground plane as close as possible for excellent RF performance.
2	VCTL	Control voltage terminal. Inputting a logic-high, the LNA turn at LNA active mode. Inputting a logic-low, the LNA turn at stand-by mode.
3	RFOUT	RF output terminal. Requires an external capacitor C1. The capacitor C1 is not only a matching component, but also a DC blocking capacitor.
4	VDD	Supply voltage terminal. Bypass to ground with capacitor C2 as close as possible to the IC.
5	GND	Ground terminal. These terminals should be connected to the ground plane as close as possible for excellent RF performance.
6	RFIN	RF input terminal. Requires a matching inductor L1. Integrated a DC blocking capacitor.

ELECTRICAL CHARACTERISTICS

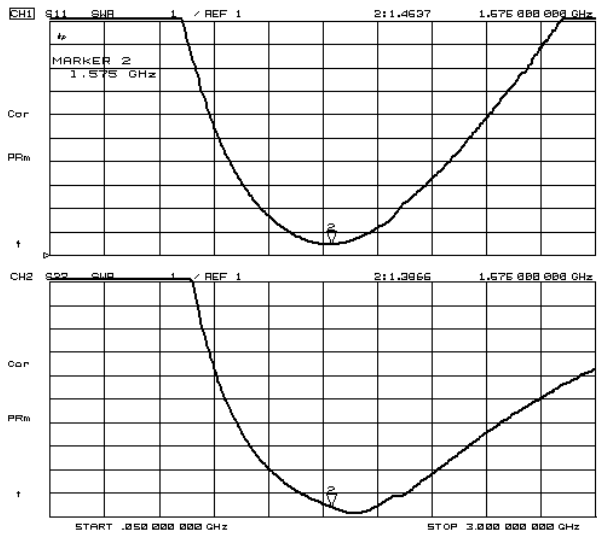
Conditions: $V_{DD}=2.85V$, $V_{CTL}=1.8V$, $T_a=+25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit



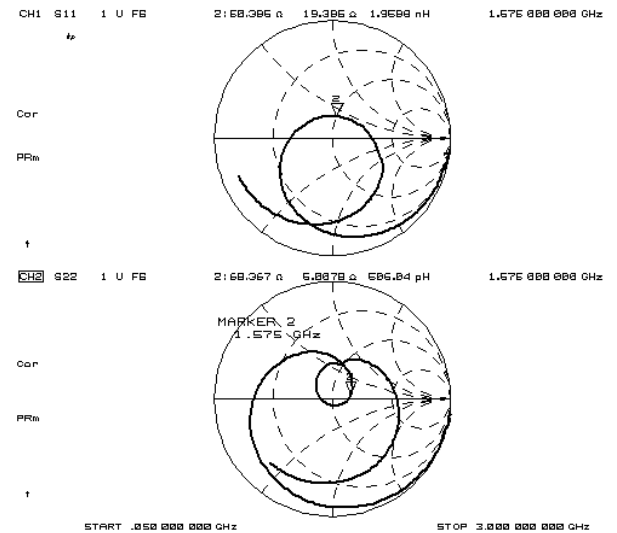
S11, S22



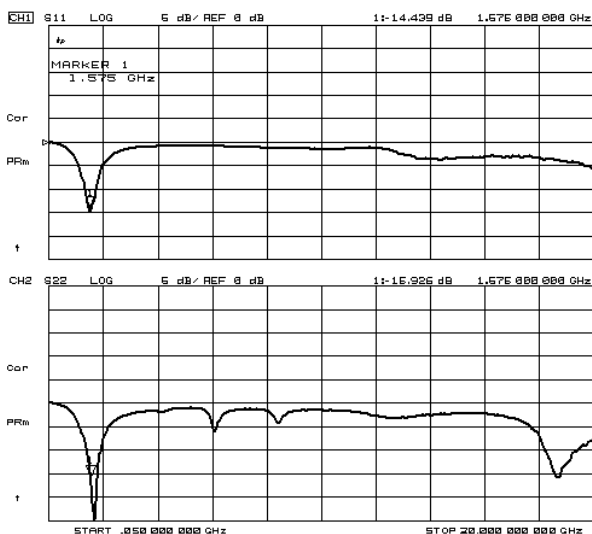
S21, S12



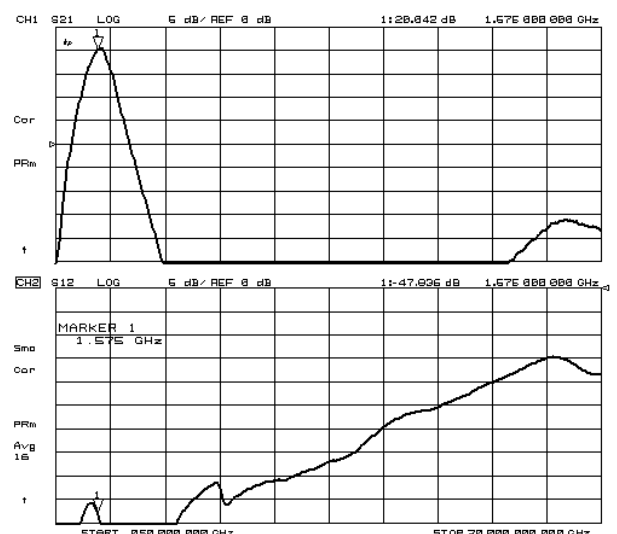
VSWR



Zin, Zout



S11, S22 (f=50MHz~20GHz)

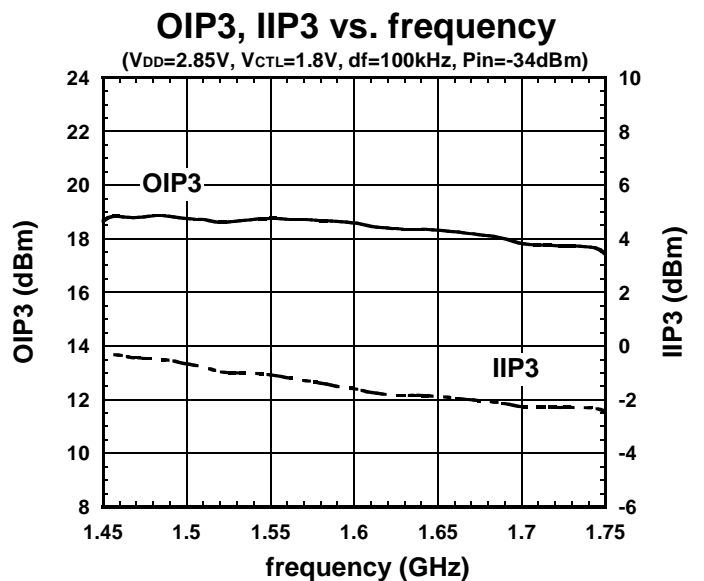
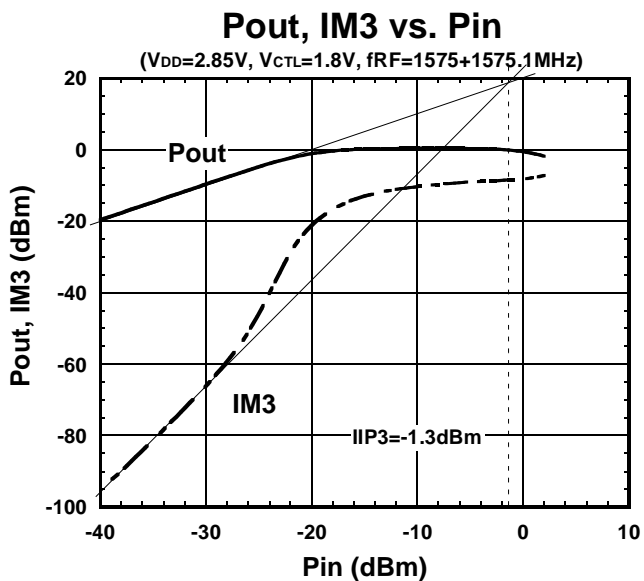
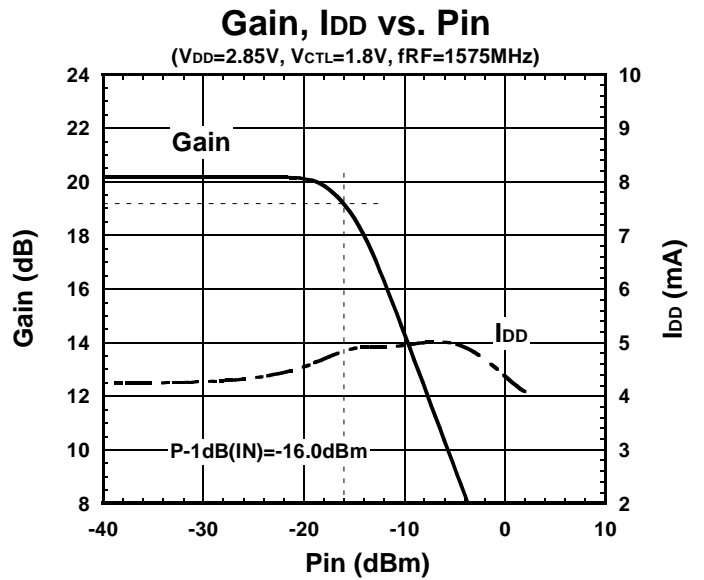
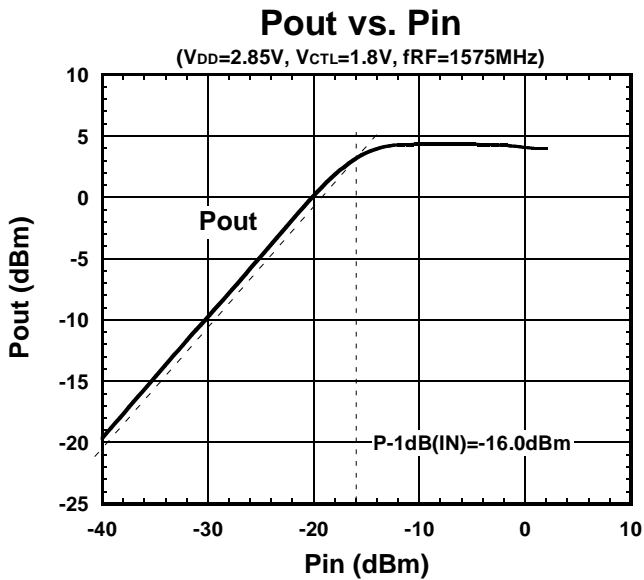
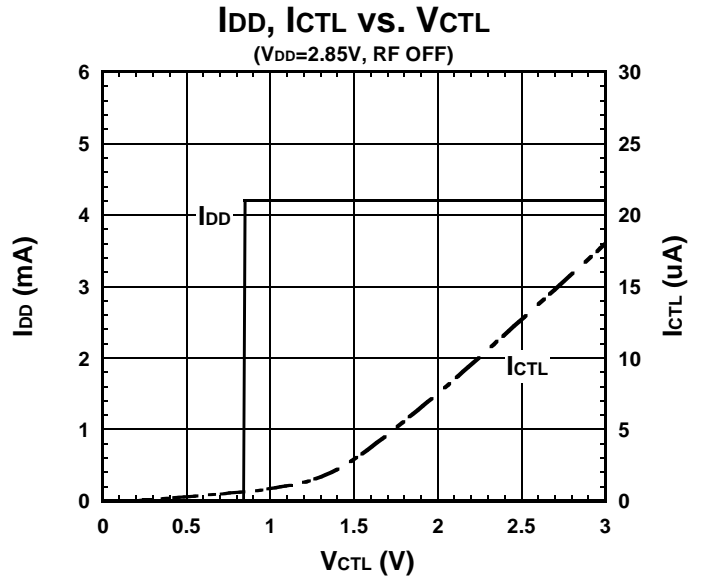
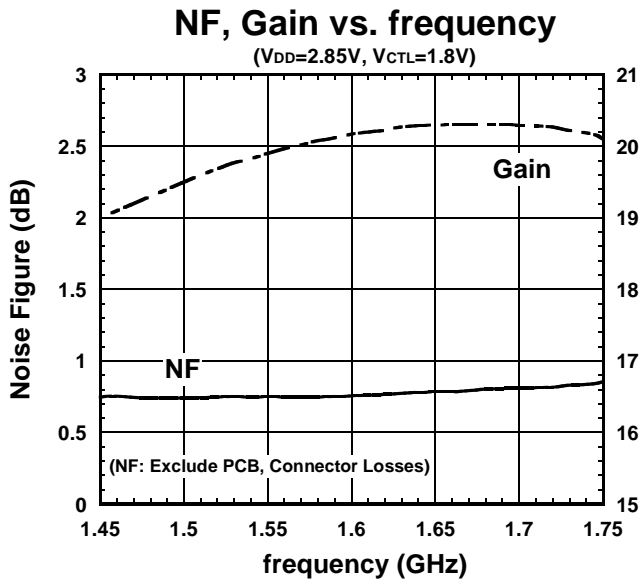


S21, S12 (f=50MHz~20GHz)

NJG1143UA2

ELECTRICAL CHARACTERISTICS

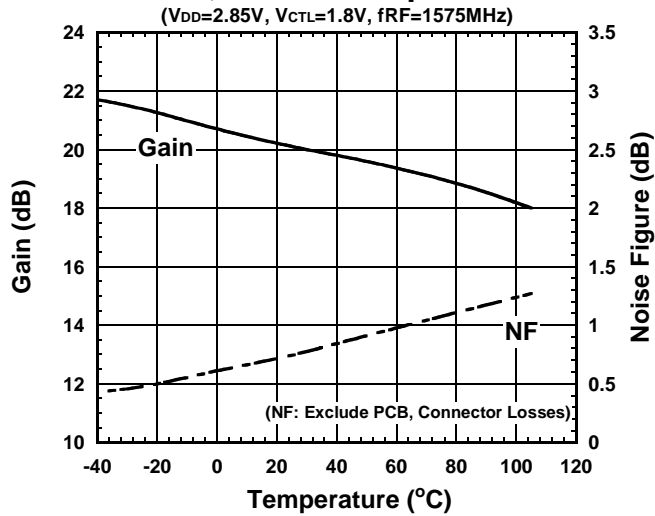
Conditions: $V_{DD}=2.85V$, $V_{CTL}=1.8V$, $T_a=+25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit



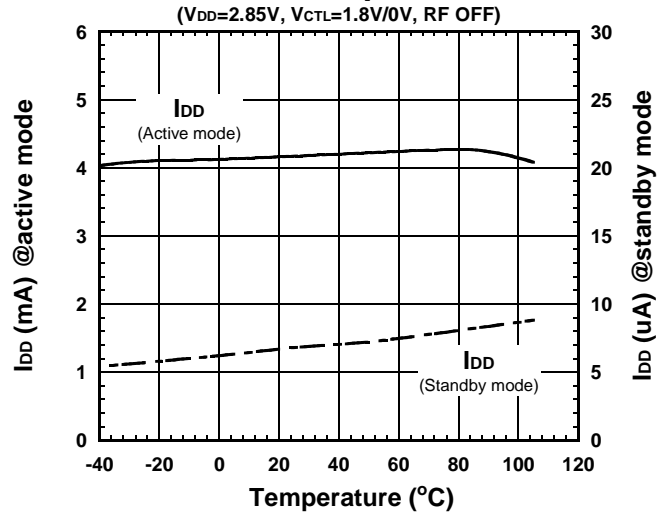
ELECTRICAL CHARACTERISTICS

Conditions: $V_{DD}=2.85V$, $V_{CTL}=1.8V$, $T_a=+25^\circ C$, $Z_s=Z_l=50\Omega$, with application circuit

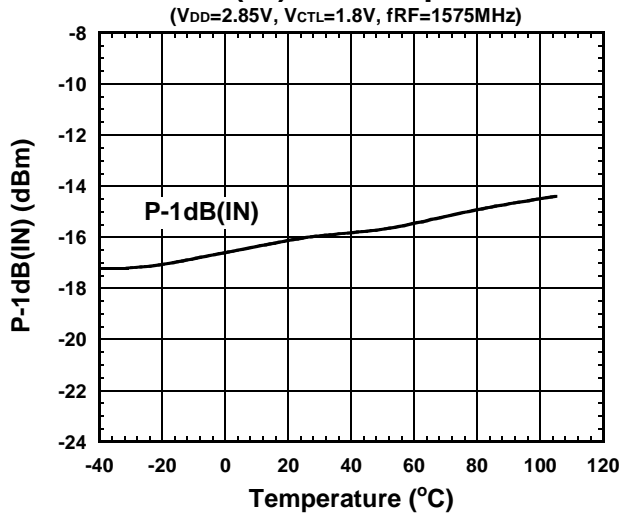
Gain, NF vs. Temperature



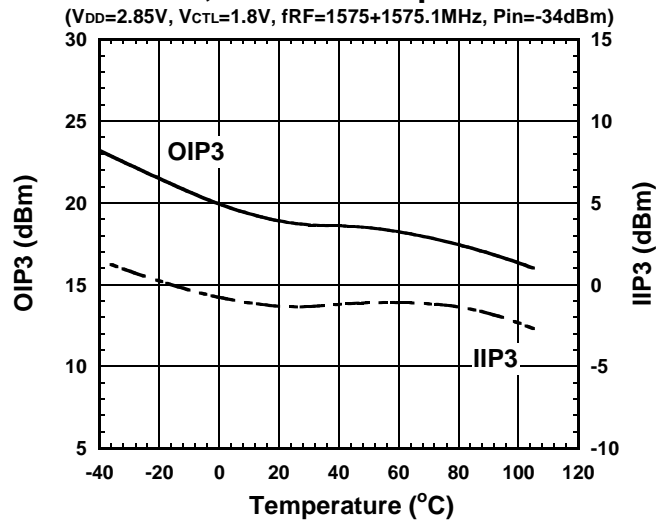
I_{DD} vs. Temperature



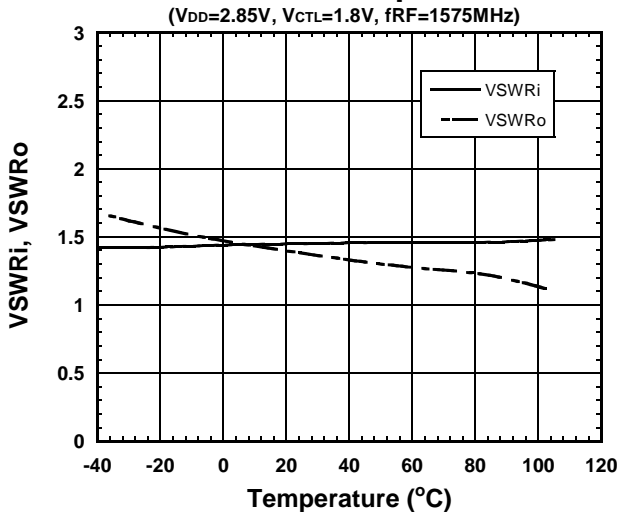
P-1dB(IN) vs. Temperature



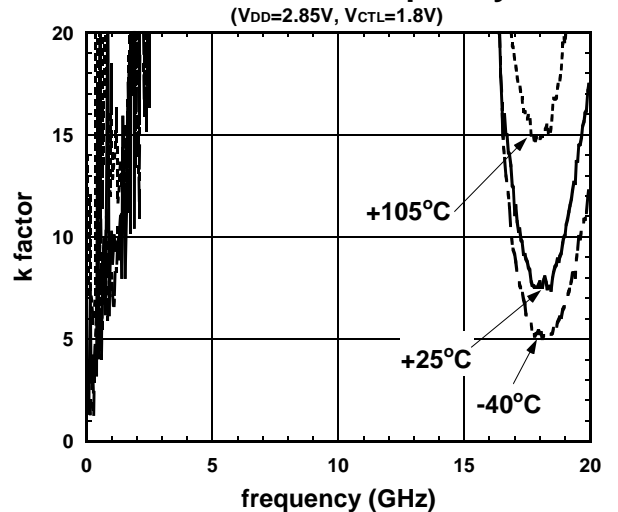
OIP3, IIP3 vs. Temperature



VSWR vs. Temperature



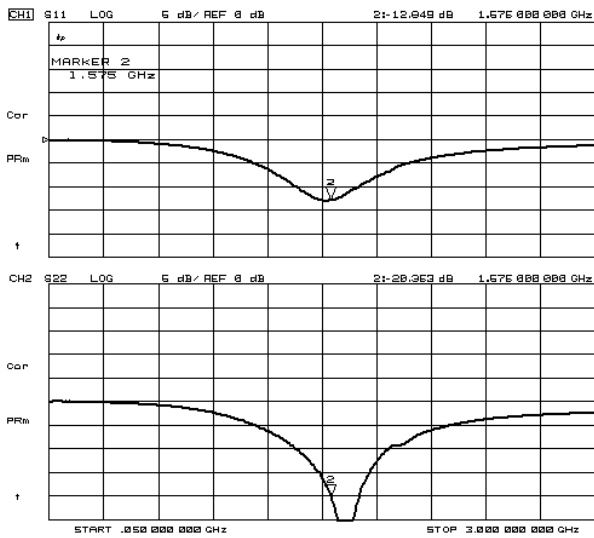
k factor vs. frequency



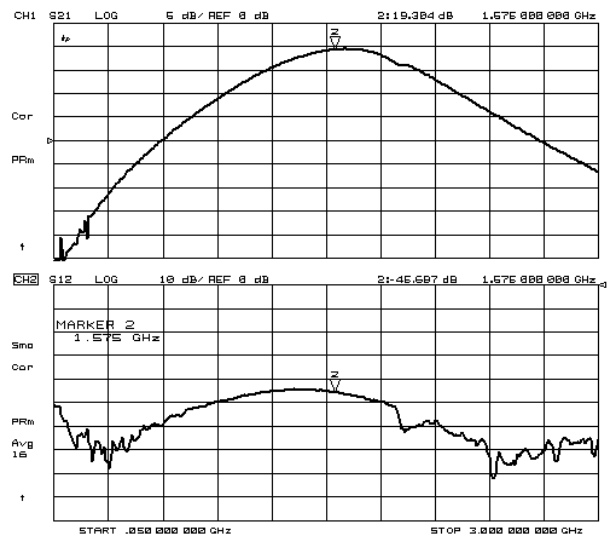
NJG1143UA2

ELECTRICAL CHARACTERISTICS

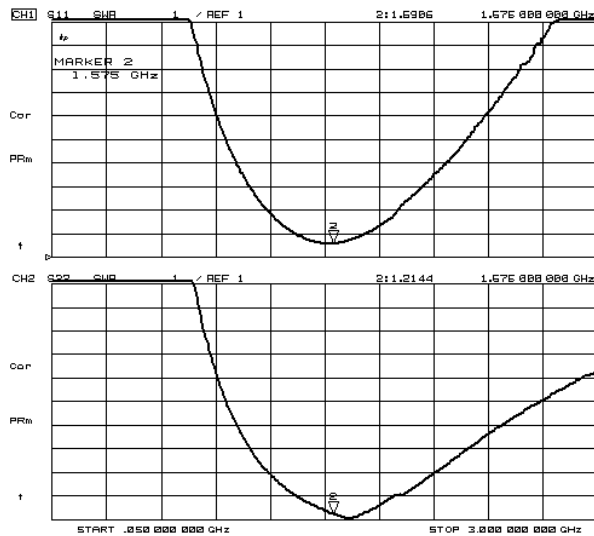
Conditions: $V_{DD}=1.8V$, $V_{CTL}=1.8V$, $T_a=+25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit



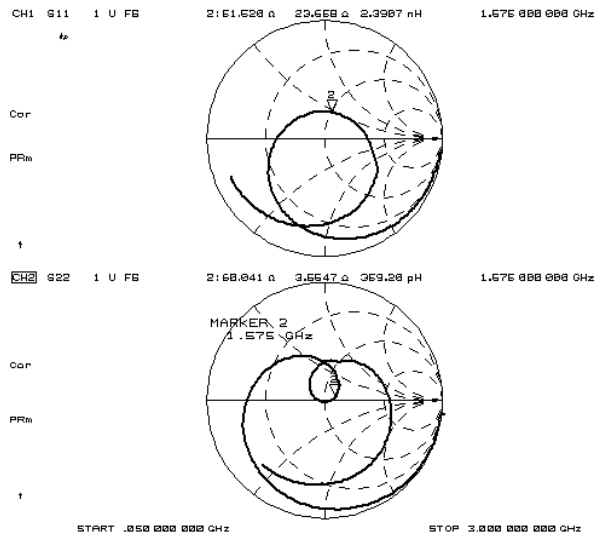
S11, S22



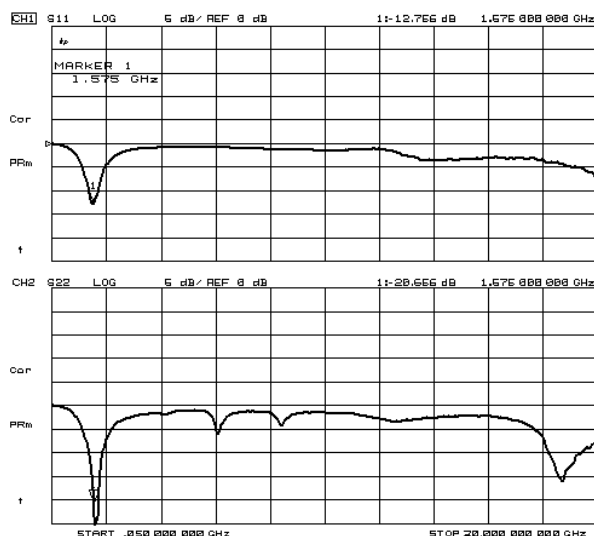
S21, S12



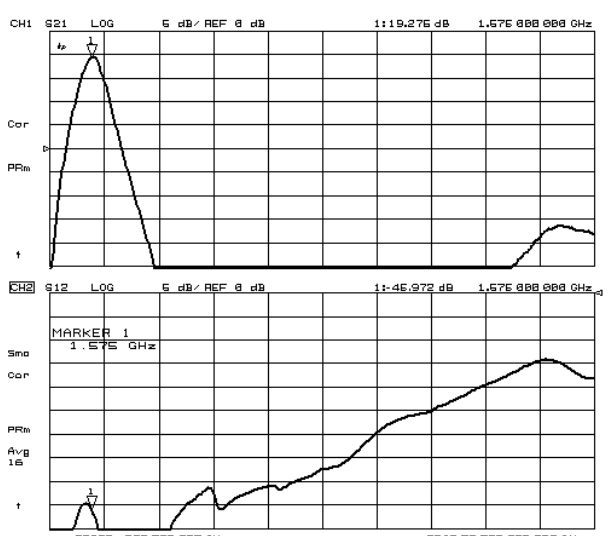
VSWR



Zin, Zout



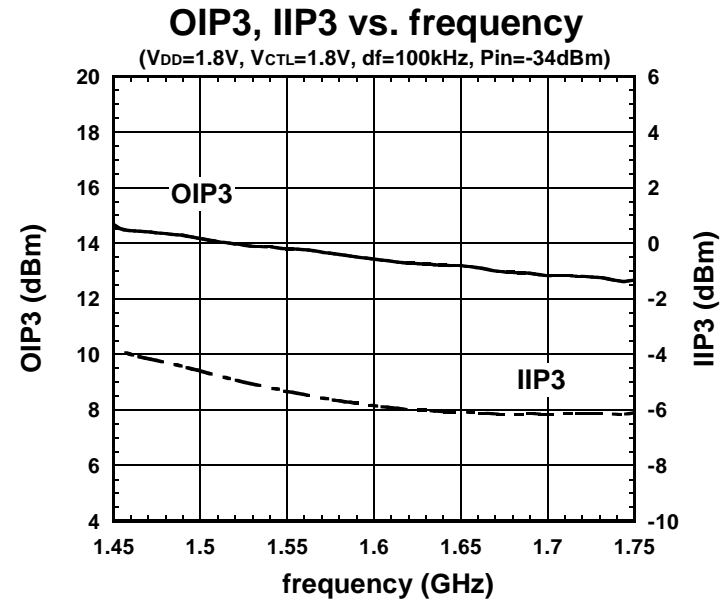
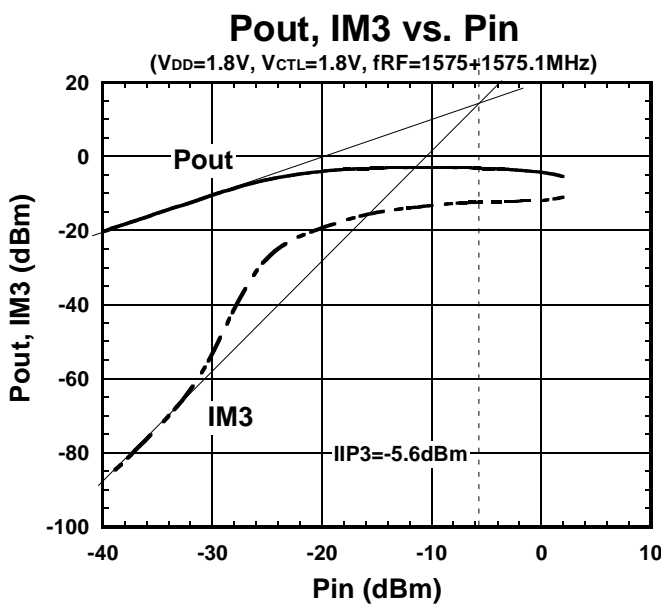
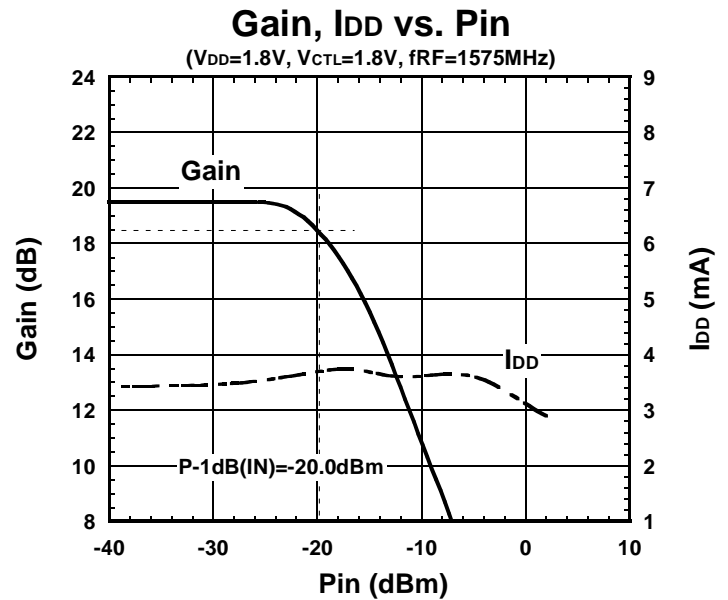
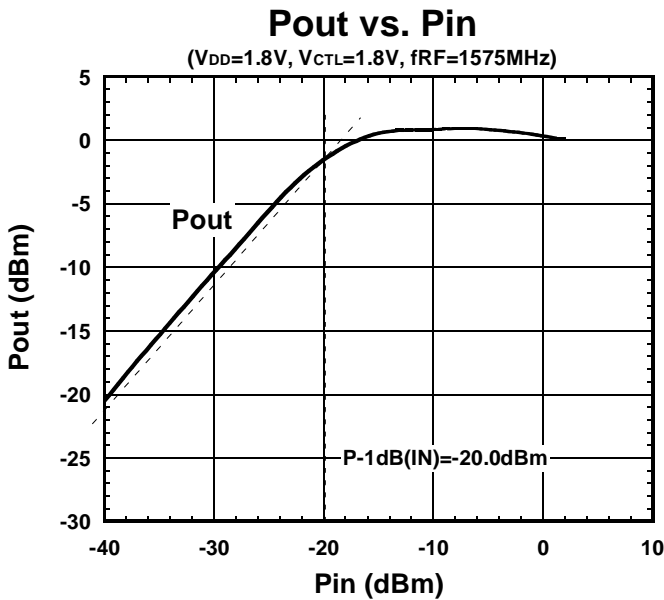
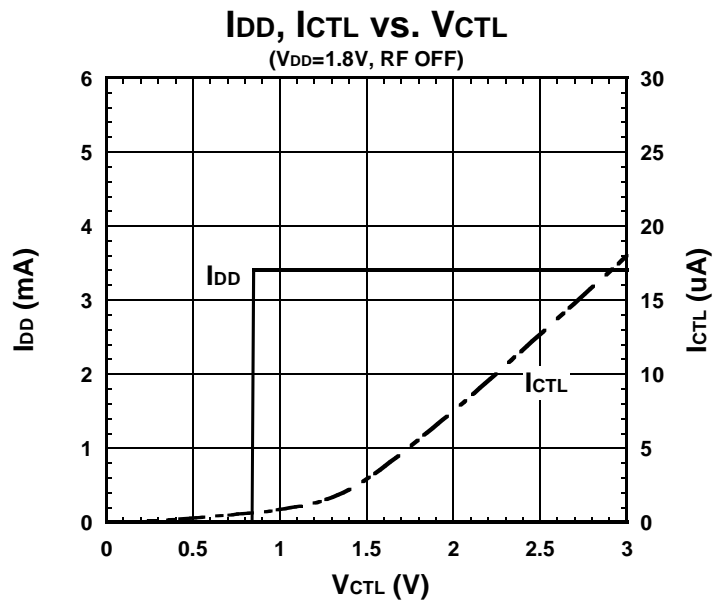
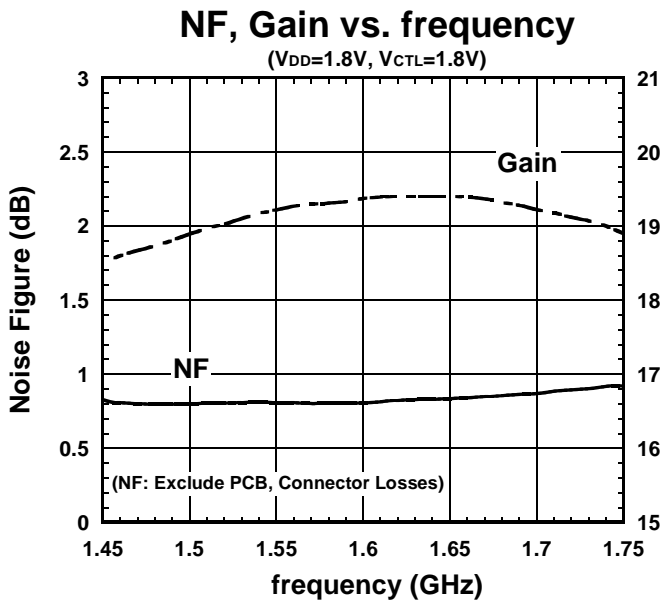
S11, S22 (f=50MHz~20GHz)



S21, S12 (f=50MHz~20GHz)

ELECTRICAL CHARACTERISTICS

Conditions: $V_{DD}=1.8V$, $V_{CTL}=1.8V$, $T_a=+25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit

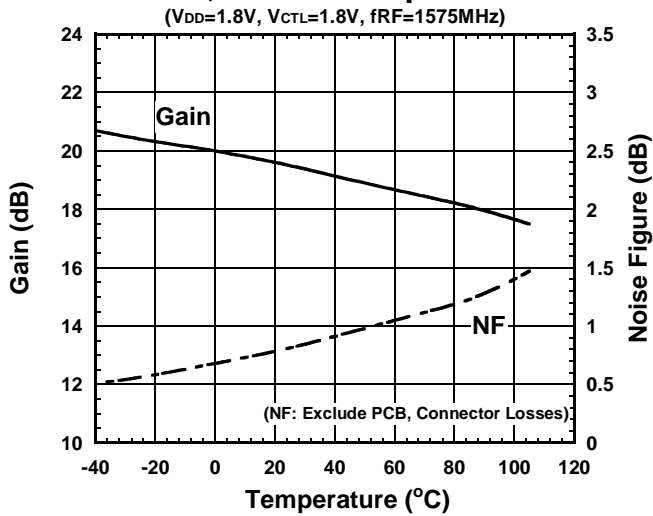


NJG1143UA2

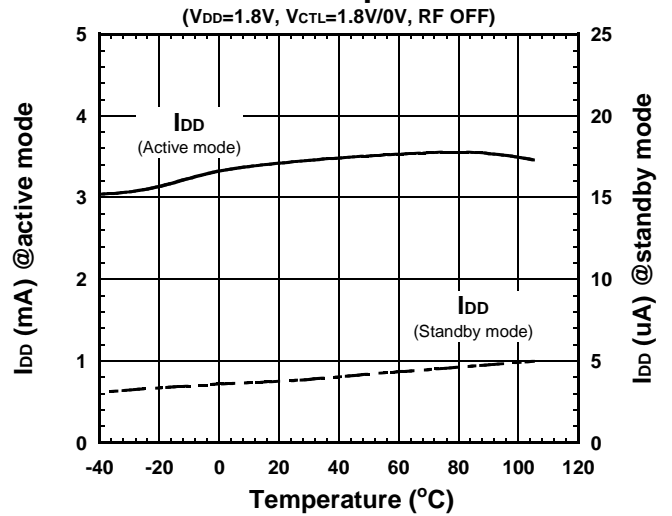
ELECTRICAL CHARACTERISTICS

Conditions: $V_{DD}=1.8V$, $V_{CTL}=1.8V$, $Z_s=Z_l=50\Omega$, with application circuit

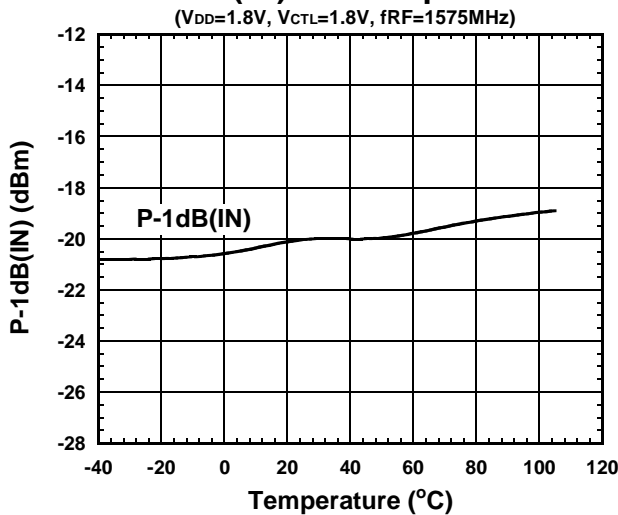
Gain, NF vs. Temperature



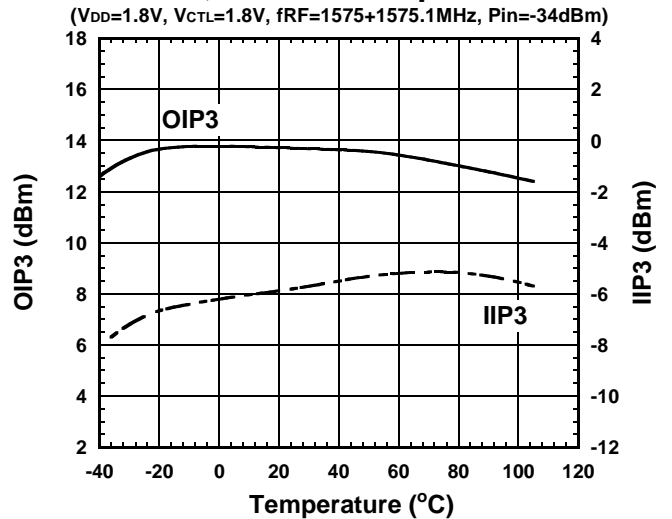
I_{DD} vs. Temperature



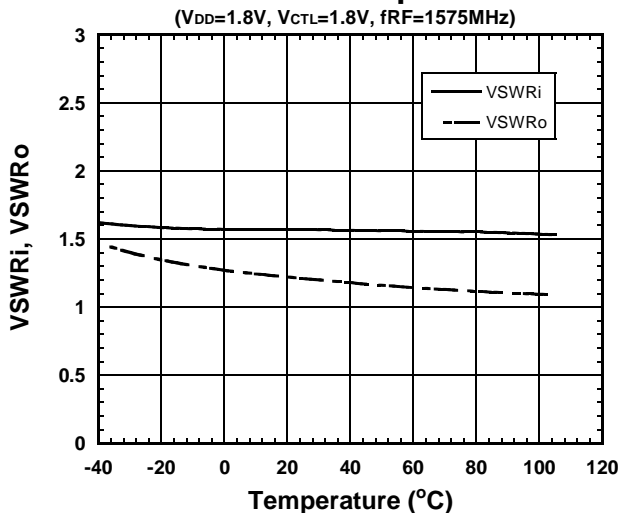
P-1dB(IN) vs. Temperature



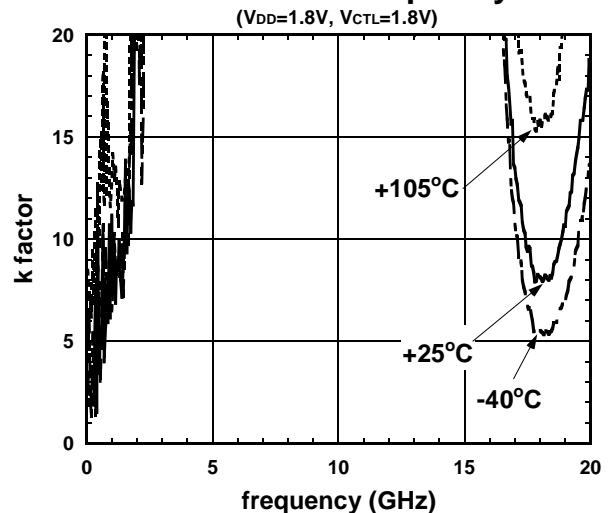
OIP3, IIP3 vs. Temperature



VSWR vs. Temperature

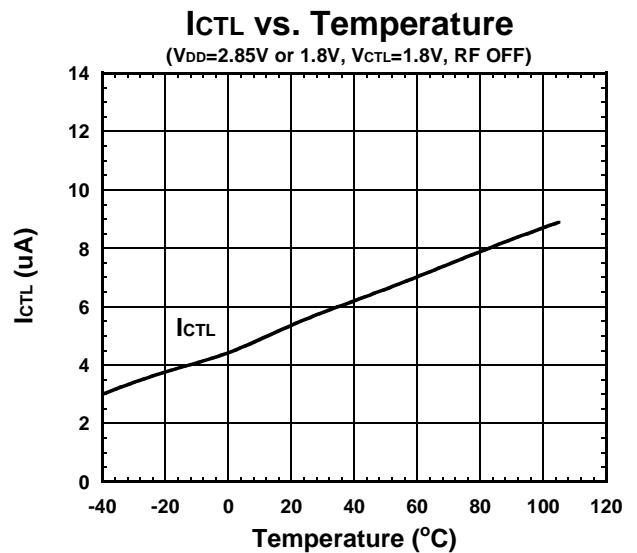
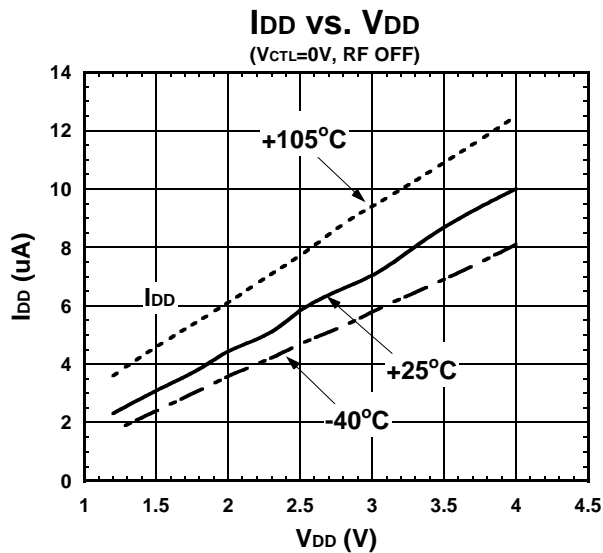
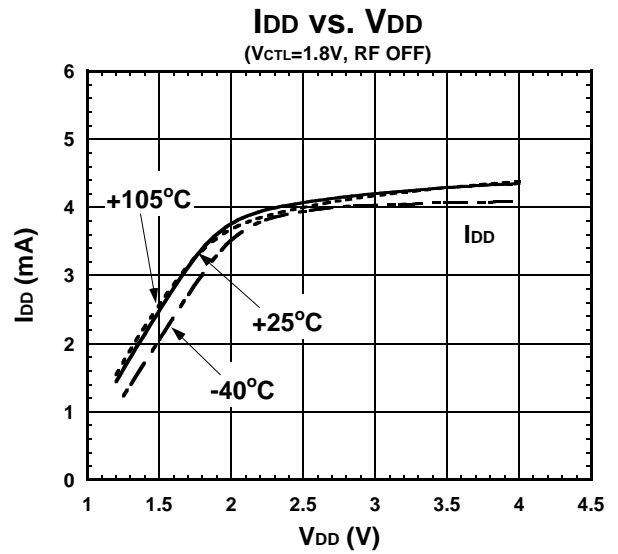
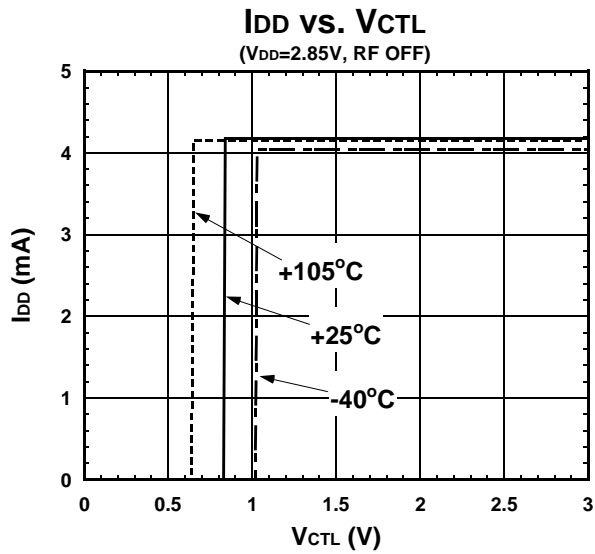


k factor vs. frequency



ELECTRICAL CHARACTERISTICS

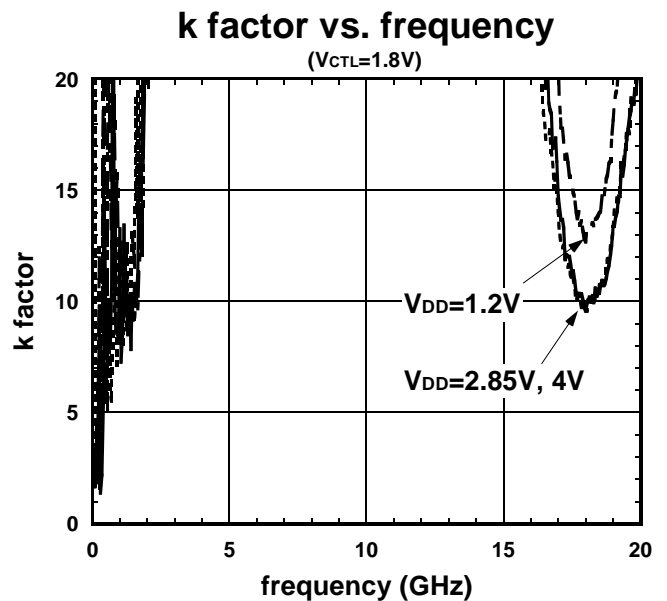
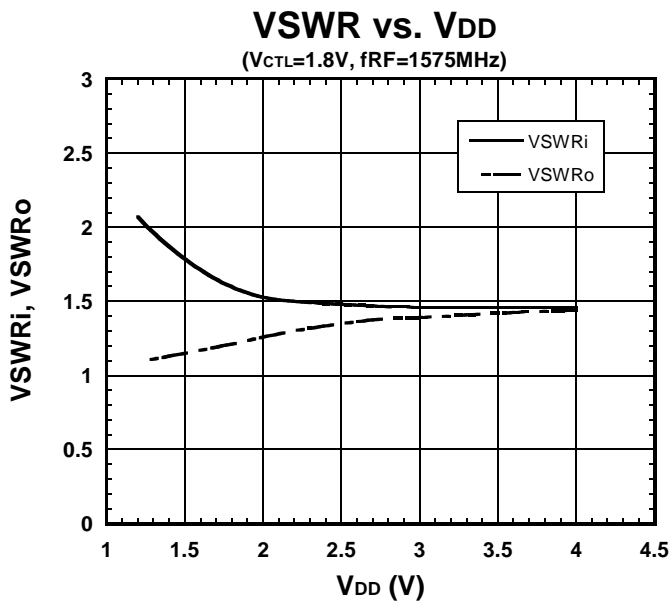
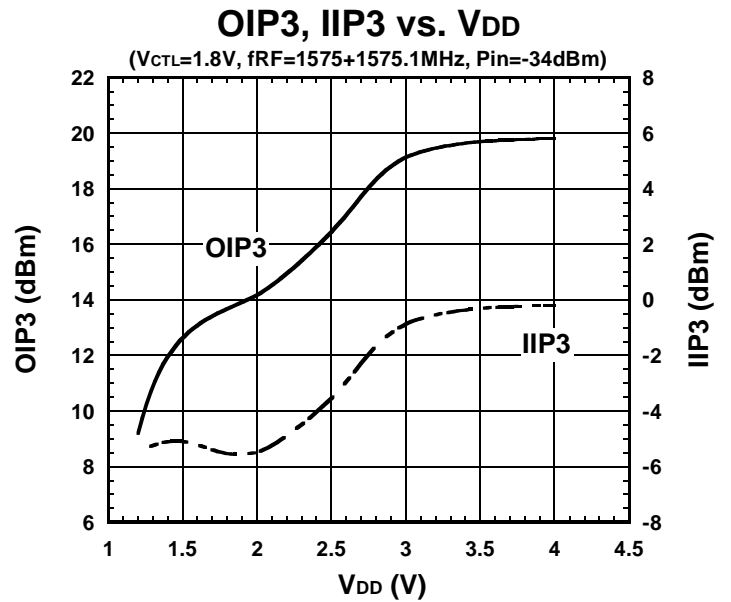
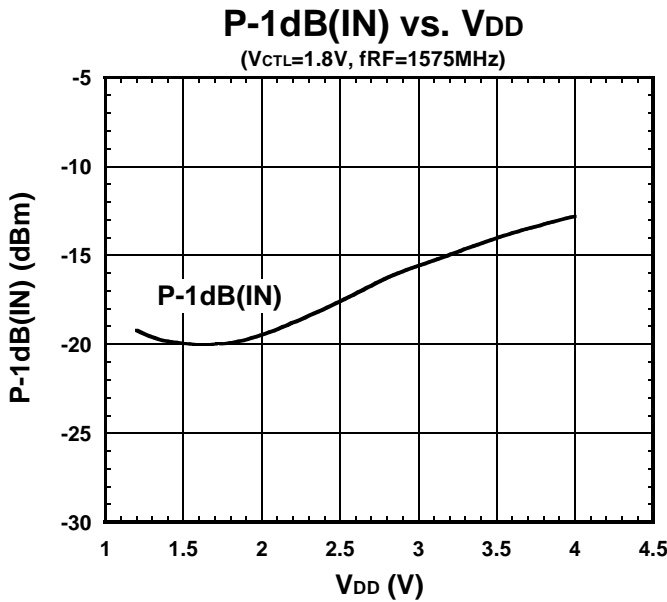
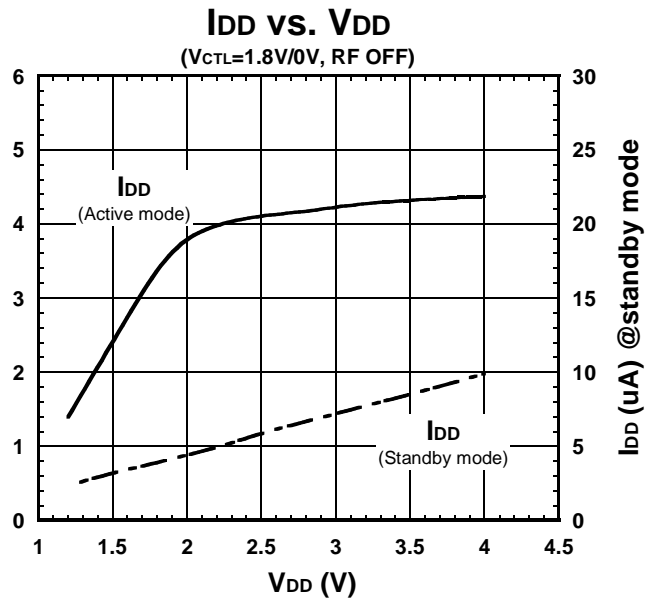
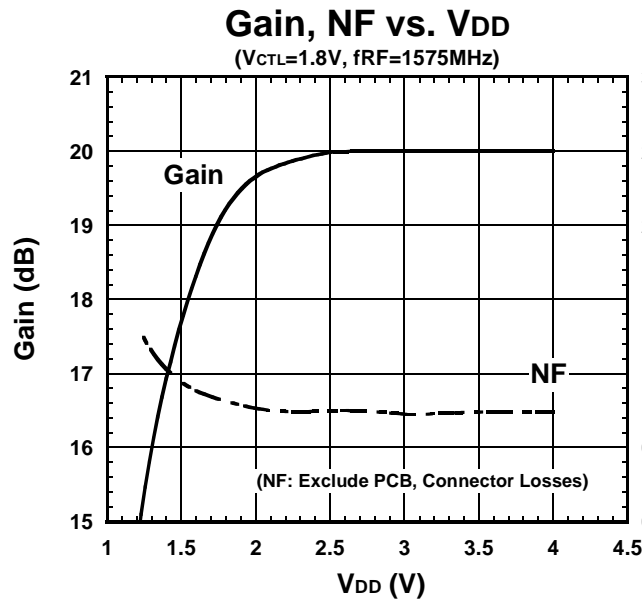
Conditions: RF OFF, $Z_s=Z_l=50\Omega$, with application circuit



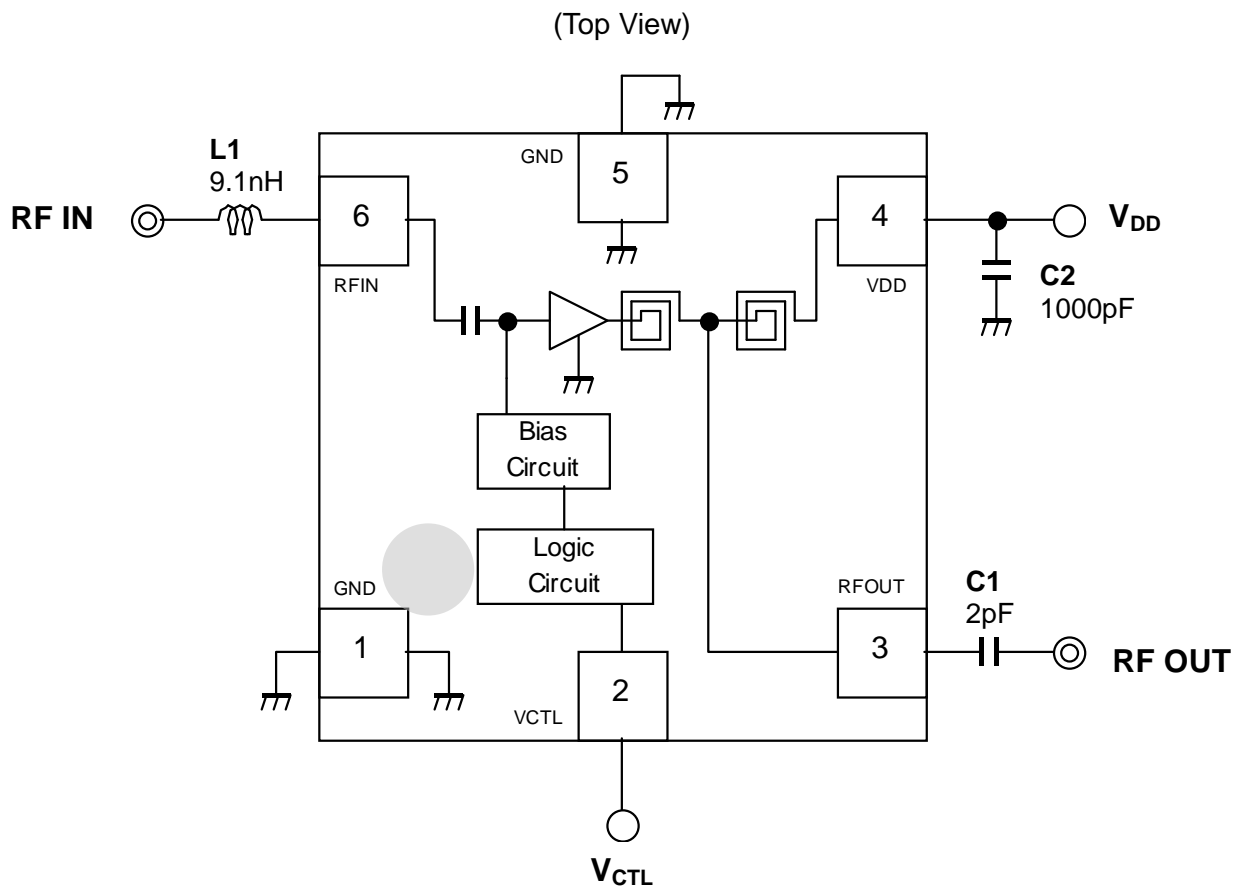
NJG1143UA2

ELECTRICAL CHARACTERISTICS

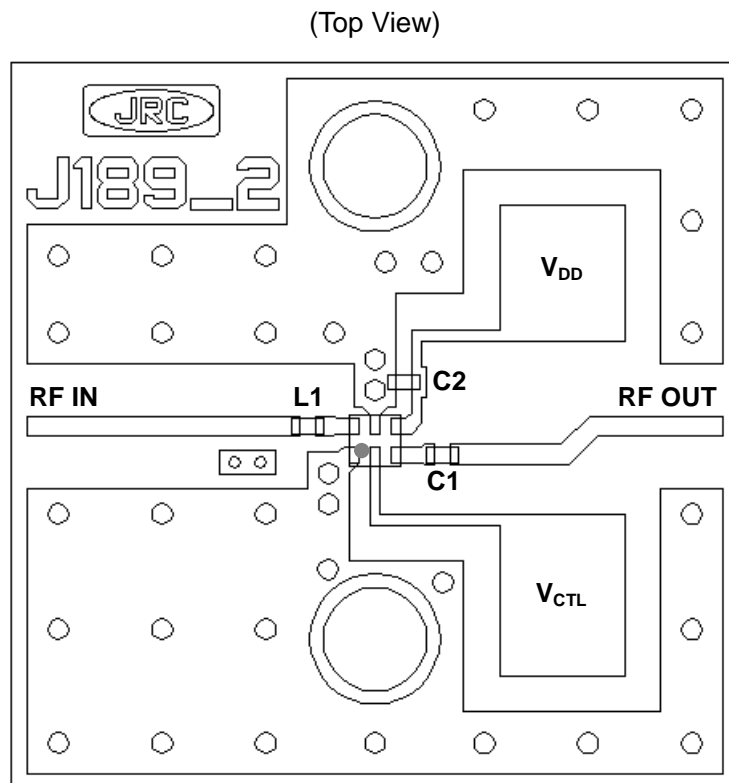
Condition: $V_{CTL}=1.8V$, $T_a=+25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit



APPLICATION CIRCUIT



TEST PCB LAYOUT



Parts list

Parts ID	Manufacture
L1	LQP03T_02 Series (MURATA)
C1, C2	GRM03 Series (MURATA)

PCB

Substrate: FR-4
 Thickness: 0.2mm
 Microstrip line width: 0.4mm ($Z_0=50\Omega$)
 Size: 14.0mm x 14.0mm

NJG1143UA2

■ NOISE FIGURE MEASUREMENT CONDITONS

Measuring instruments

NF Analyzer : Agilent 8973A, 8975A

Noise Source : Agilent 346A

Setting the NF analyzer

Measurement mode form

Device under test : Amplifier

System downconverter : off

Mode setup form

Sideband : LSB

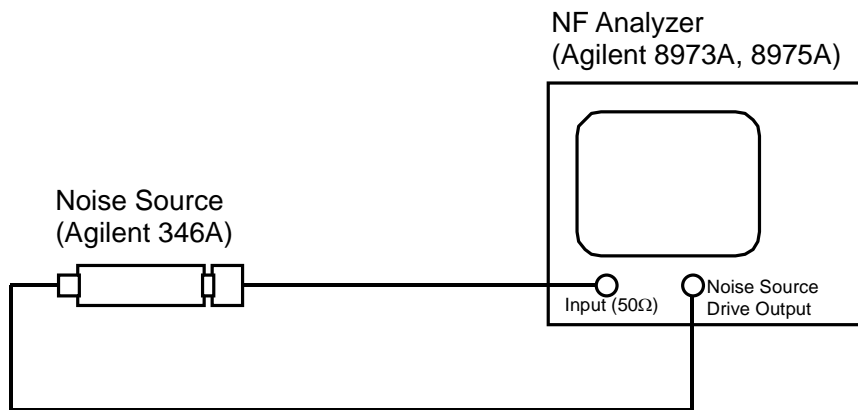
Averages : 16

Average mode : Point

Bandwidth : 4MHz

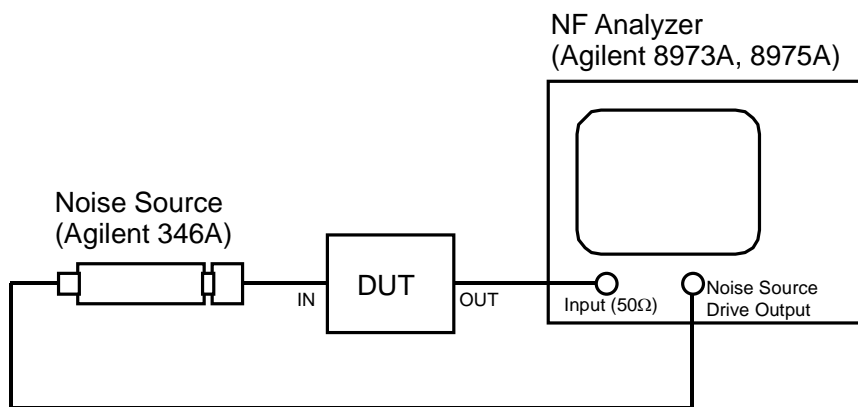
Loss comp : off

Tcold : setting the temperature of noise source (303.15K)



* Noise source and NF analyzer are connected directly.

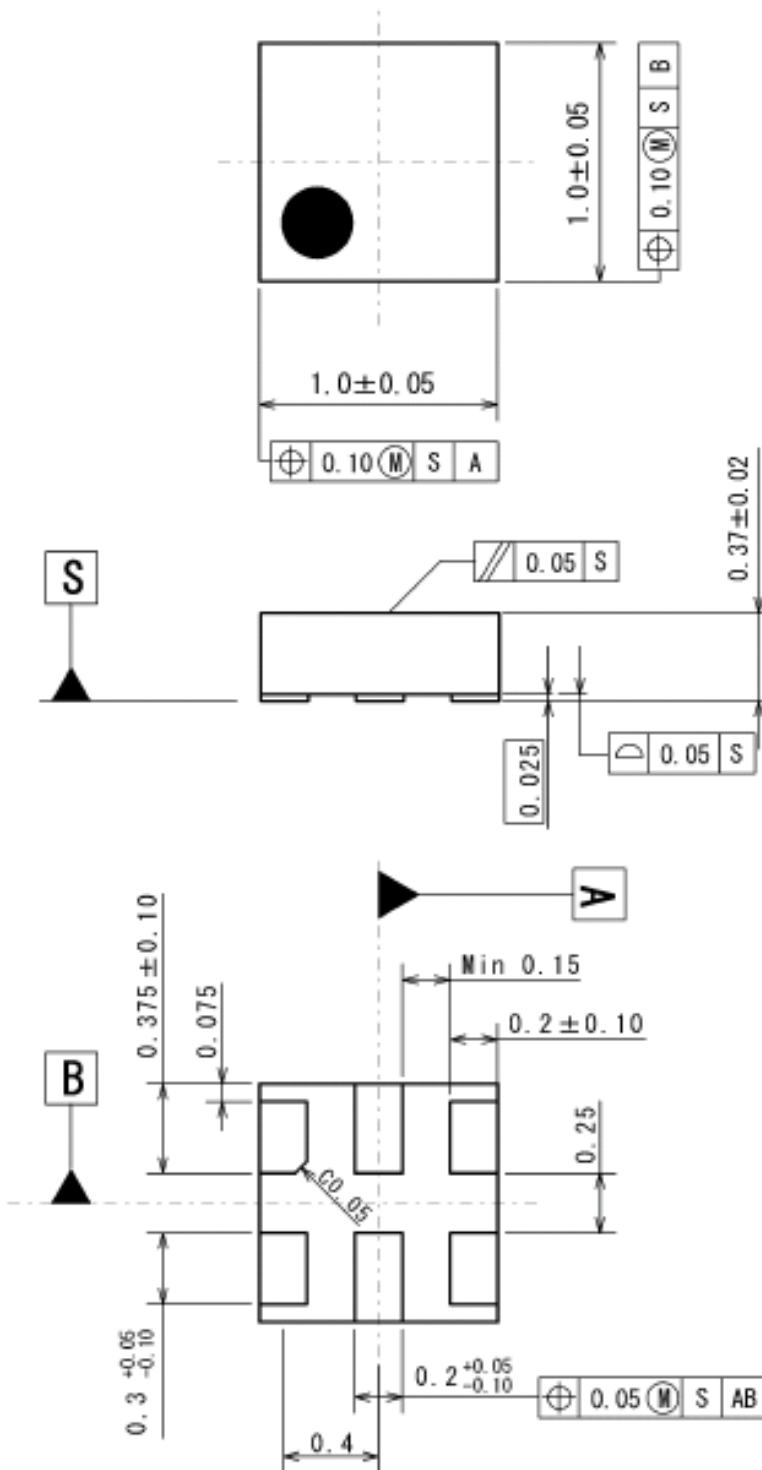
Calibration Setup



* Noise source and DUT, DUT and NF analyzer are connected directly.

Measurement Setup

PACKAGE OUTLINE (EPFFP6-A2)



Unit	: mm
Substrate	: FR4
Terminal treat	: Au
Molding material	: Epoxy resin
Weight (typ.)	: 0.855mg

Cautions on using this product

This product contains Gallium-Arsenide (GaAs) which is a harmful material.

- Do NOT eat or put into mouth.
- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.
- To waste this product, please obey the relating law of your country.

This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.

[CAUTION]

The specifications on this databook are only given for information, without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [RF Amplifier](#) category:

Click to view products by [Nisshinbo](#) manufacturer:

Other Similar products are found below :

[A82-1](#) [BGA622H6820XTSA1](#) [BGA 728L7 E6327](#) [BGB719N7ESDE6327XTMA1](#) [HMC397-SX](#) [HMC405](#) [HMC561-SX](#) [HMC8120-SX](#)
[HMC8121-SX](#) [HMC-ALH382-SX](#) [HMC-ALH476-SX](#) [SE2433T-R](#) [SMA3101-TL-E](#) [SMA39](#) [A66-1](#) [A66-3](#) [A67-1](#) [LX5535LQ](#) [LX5540LL](#)
[MAAM02350](#) [HMC3653LP3BETR](#) [HMC549MS8GETR](#) [HMC-ALH435-SX](#) [SMA101](#) [SMA32](#) [SMA411](#) [SMA531](#) [SST12LP17E-XX8E](#)
[SST12LP19E-QX6E](#) [WPM0510A](#) [HMC5929LS6TR](#) [HMC5879LS7TR](#) [HMC1126](#) [HMC1087F10](#) [HMC1086](#) [HMC1016](#) [SMA1212](#)
[MAX2689EWS+T](#) [MAAMSS0041TR](#) [MAAM37000-A1G](#) [LTC6430AIUF-15#PBF](#) [CHA5115-QDG](#) [SMA70-2](#) [SMA4011](#) [A231](#) [HMC-](#)
[AUH232](#) [LX5511LQ](#) [LX5511LQ-TR](#) [HMC7441-SX](#) [HMC-ALH310](#)